

SiT3809

80 MHz to 220 MHz MEMS VCXO



Features

- Any frequency between 80.000001 MHz and 220 MHz with 6 decimal places of accuracy
- 100% pin-to-pin drop-in replacement to quartz-based VCXO
- Frequency stability as tight as ± 10 ppm
- Widest pull range options from ± 25 ppm to ± 1600 ppm
- Industrial or extended commercial temperature range
- Superior pull range linearity of $\leq 1\%$, 10 times better than quartz
- LVCMOS/LVTTL compatible output
- Four industry-standard packages: 2.5 mm x 2.0 mm (4-pin), 3.2 mm x 2.5 mm (4-pin), 5.0 mm x 3.2 mm (6-pin), 7.0 mm x 5.0 mm (6-pin)
- Instant samples with [Time Machine II](#) and [field programmable oscillators](#)
- RoHS and REACH compliant, Pb-free, Halogen-free and Antimony-free

Applications

- Telecom clock synchronization, instrumentation
- Low bandwidth analog PLL, jitter cleaner, clock recovery, audio
- Video, 3G/HD-SDI, FPGA, broadband and networking



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Electrical Specifications

Table 1. Electrical Characteristics^[1, 2, 3]

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Condition |
|--|---------|---|------|------|------|---|
| Frequency Range | | | | | | |
| Output Frequency Range | f | 80.000001 | – | 220 | MHz | |
| Frequency Stability and Aging | | | | | | |
| Frequency Stability | F_stab | -10 | – | +10 | ppm | Inclusive of Initial tolerance ^[4] at 25°C, and variation over temperature, rated supply voltage and load. |
| | | -25 | – | +25 | ppm | |
| | | -50 | – | +50 | ppm | |
| Aging | F_aging | -5 | – | +5 | ppm | 10 years, 25°C |
| Operating Temperature Range | T_use | -20 | – | +70 | °C | Extended Commercial |
| | | -40 | – | +85 | °C | Industrial |
| Supply Voltage and Current Consumption | | | | | | |
| Supply Voltage | Vdd | 1.71 | 1.8 | 1.89 | V | Additional supply voltages between 2.5V and 3.3V can be supported. Contact SiTime for additional information. |
| | | 2.25 | 2.5 | 2.75 | V | |
| | | 2.52 | 2.8 | 3.08 | V | |
| | | 2.97 | 3.3 | 3.63 | V | |
| Current Consumption | Idd | – | 34 | 36 | mA | No load condition, f = 100 MHz, Vdd = 2.5V, 2.8V or 3.3V |
| | | – | 30 | 33 | mA | No load condition, f = 100 MHz, Vdd = 1.8V |
| Standby Current | I_std | – | – | 70 | μA | Vdd = 2.5V, 2.8V, 3.3V, \overline{ST} = GND, output is Weakly Pulled Down |
| | | – | – | 10 | μA | Vdd = 1.8V, \overline{ST} = GND, output is Weakly Pulled Down |
| VCXO Characteristics | | | | | | |
| Pull Range ^[5, 6] | PR | ±25, ±50, ±100, ±150, ±200, ±400, ±800, ±1600 | | | ppm | See the Absolute Pull Range and APR table on page 8 |
| Upper Control Voltage | VC_U | 1.7 | – | – | V | Vdd = 1.8V, Voltage at which maximum deviation is guaranteed. |
| | | 2.4 | – | – | V | Vdd = 2.5V, Voltage at which maximum deviation is guaranteed. |
| | | 2.7 | – | – | V | Vdd = 2.8V, Voltage at which maximum deviation is guaranteed. |
| | | 3.2 | – | – | V | Vdd = 3.3V, Voltage at which maximum deviation is guaranteed. |
| Lower Control Voltage | VC_L | – | – | 0.1 | V | Voltage at which minimum deviation is guaranteed. |
| Control Voltage Input Impedance | Z_in | 100 | – | – | kΩ | |
| Control Voltage Input Capacitance | C_in | – | 5 | – | pF | |
| Linearity | Lin | – | 0.1 | 1 | % | |
| Frequency Change Polarity | – | Positive slope | | | – | |
| Control Voltage Bandwidth (-3dB) | V_BW | – | 8 | – | kHz | Contact SiTime for 16 kHz and other high bandwidth options |

Electrical Specifications (continued)

Table 1. Electrical Characteristics^[1, 2, 3]

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Condition |
|---------------------------------------|----------|------|------|------|------|--|
| LVC MOS Output Characteristics | | | | | | |
| Duty Cycle | DC | 45 | – | 55 | % | f ≤ 165 MHz, all Vdds. Refer to Note 11 for definition of Duty Cycle. |
| | | 40 | – | 60 | % | f > 165 MHz, all Vdds. Refer to Note 11 for definition of Duty Cycle. |
| Rise/Fall Time | Tr, Tf | – | 1.5 | 2 | ns | Vdd = 1.8V, 2.5V, 2.8V or 3.3V, 10% - 90% Vdd level |
| Output High Voltage | VOH | 90% | – | – | Vdd | IOH = -7 mA (Vdd = 3.0V or 3.3V) IOH = -4 mA (Vdd = 2.8V or 2.5V) IOH = -2 mA (Vdd = 1.8V) |
| Output Low Voltage | VOL | – | – | 10% | Vdd | IOL = 7 mA (Vdd = 3.0V or 3.3V) IOL = 4 mA (Vdd = 2.8V or 2.5V) IOL = 2 mA (Vdd = 1.8V) |
| Input Characteristics | | | | | | |
| Input Pull-up Impedance | Z_in | – | 100 | 250 | kΩ | For the OE/ $\overline{\text{ST}}$ pin for 6-pin devices |
| Input Capacitance | C_in | – | 5 | – | pF | For the OE/ $\overline{\text{ST}}$ pin for 6-pin devices |
| Startup and Resume Timing | | | | | | |
| Startup Time | T_start | – | – | 10 | ms | See Figure 7 for startup resume timing diagram |
| OE Enable/Disable Time | T_oe | – | – | 115 | ns | f = 80.000001 MHz, all Vdds. For other freq, T_oe = 100 ns + 3 clock periods |
| Resume Time | T_resume | – | 7 | 10 | ms | See Figure 8 for resume timing diagram |
| Jitter | | | | | | |
| RMS Period Jitter | T_jitt | – | 1.5 | 2 | ps | f = 156.25 MHz, Vdd = 2.5V, 2.8V or 3.3V |
| | | – | 2 | 3 | ps | f = 156.25 MHz, Vdd = 1.8V |
| RMS Phase Jitter (random) | T_phj | – | 0.5 | 1 | ps | f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz |

Notes:

1. All electrical specifications in the above table are specified with 15 pF output load and for all Vdd(s) unless otherwise stated.
2. The typical value of any parameter in the Electrical Characteristics table is specified for the nominal value of the highest voltage option for that parameter and at 25°C temperature.
3. All max and min specifications are guaranteed across rated voltage variations and operating temperature ranges, unless specified otherwise.
4. Initial tolerance is measured at Vin = Vdd/2
5. Absolute Pull Range (APR) is defined as the guaranteed pull range over temperature and voltage.
6. APR = pull range (PR) - frequency stability (F_stab) - Aging (F_aging)

SiT3809

80 MHz to 220 MHz MEMS VCXO

Table 2. Pin Description. 4-Pin Configuration
(For 2.5 x 2.0 mm and 3.2 x 2.5 mm packages)

| Pin | Symbol | | Functionality |
|-----|--------|-------------|--|
| 1 | VIN | Input | 0-Vdd: produces voltage dependent frequency change |
| 2 | GND | Power | Electrical ground |
| 3 | CLK | Power | Power supply voltage |
| 4 | VDD | Input Power | Oscillator output power ^[7] |

Note:

7. A capacitor value of 0.1 μ F between VDD and GND is recommended.

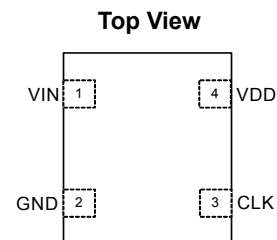


Figure 1.

Table 3. Pin Description. 6-Pin Configuration
(For 5.0 x 3.2 mm and 7.0 x 5.0 mm packages)

| Pin | Symbol | | Functionality |
|-----|----------|---------------|---|
| 1 | VIN | Input | 0-Vdd: produces voltage dependent frequency change |
| 2 | NC/OE/ST | No Connect | H or L or Open: No effect on output frequency or other device functions |
| | | Output Enable | H or Open ^[8] : specified frequency output L: output is high |
| | | Standby | H or Open ^[8] : specified frequency output L: output is low (weak pull down) ^[9] . Oscillation stops |
| 3 | GND | Power | Electrical ground |
| 4 | CLK | Output | Oscillator output |
| 5 | NC | No Connect | H or L or Open: No effect on output frequency or other device functions |
| 6 | VDD | Power | Power supply voltage ^[10] |

Notes:

8. In OE or ST mode, a pull-up resistor of 10 k Ω or less is recommended if pin 2 in the 6-pin package is not externally driven. If pin 2 needs to be left floating, use the NC option

9. Typical value of the weak pull-down impedance is 5 m Ω

10. A capacitor value of 0.1 μ F between VDD and GND is recommended.

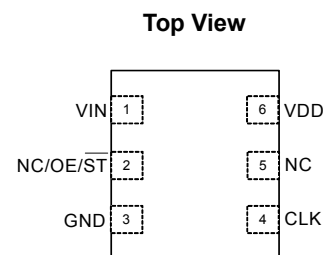


Figure 2.

Table 4. Absolute Maximum Limits

Attempted operation outside the absolute maximum ratings may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

| Parameter | Min. | Max. | Unit |
|--|------|------|------|
| Storage Temperature | -65 | 150 | °C |
| VDD | -0.5 | 4 | V |
| Electrostatic Discharge | – | 2000 | V |
| Soldering Temperature (follow standard Pb free soldering guidelines) | – | 260 | °C |

Table 5. Thermal Consideration

| Parameter | θ JA, 4 Layer Board (°C/W) | θ JA, 2 Layer Board (°C/W) | θ JC, Bottom (°C/W) |
|-----------|-----------------------------------|-----------------------------------|----------------------------|
| 7050 | 191 | 263 | 30 |
| 5032 | 97 | 199 | 24 |
| 3225 | 109 | 212 | 27 |
| 2520 | 117 | 222 | 26 |

Table 6. Environmental Compliance

| Parameter | Condition/Test Method |
|----------------------------|---------------------------|
| Mechanical Shock | MIL-STD-883F, Method 2002 |
| Mechanical Vibration | MIL-STD-883F, Method 2007 |
| Temperature Cycle | JESD22, Method A104 |
| Solderability | MIL-STD-883F, Method 2003 |
| Moisture Sensitivity Level | MSL1 @ 260°C |

Phase Noise Plot

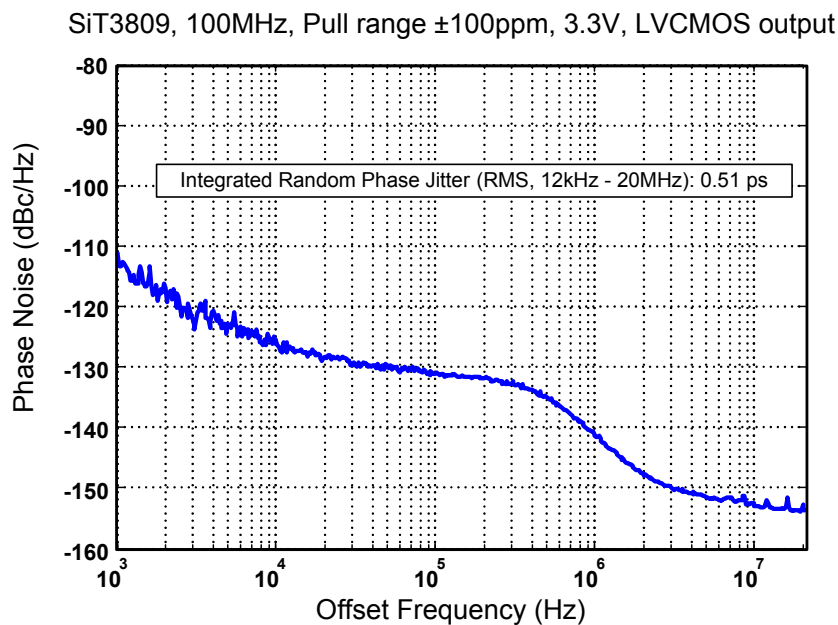


Figure 3. Phase Noise

Test Circuit and Waveform

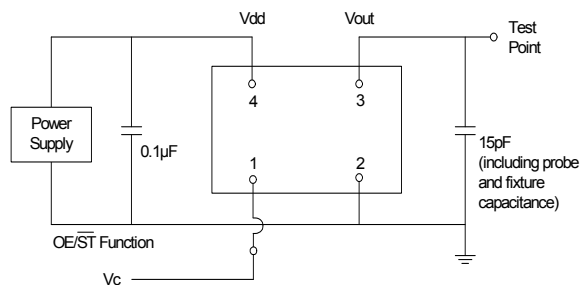


Figure 4. Test Circuit (4-Pin Device)

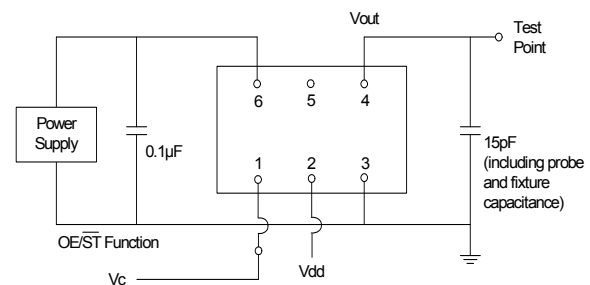


Figure 5. Test Circuit (6-Pin Device)

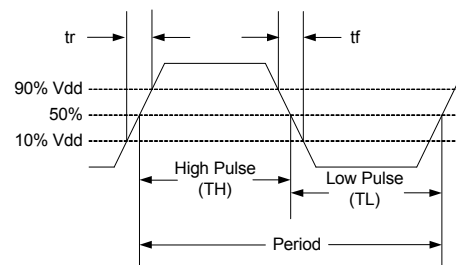


Figure 6. Waveform

Notes:

11. Duty Cycle is computed as Duty Cycle = TH/Period.
12. SiT3809 supports the configurable duty cycle feature. For custom duty cycle at any given frequency, contact [SiTime](http://www.sitime.com).

Timing Diagram

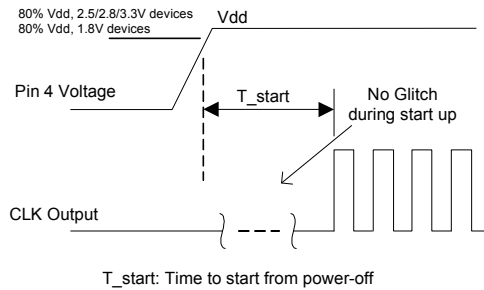


Figure 7. Startup Timing (OE/ST Mode)

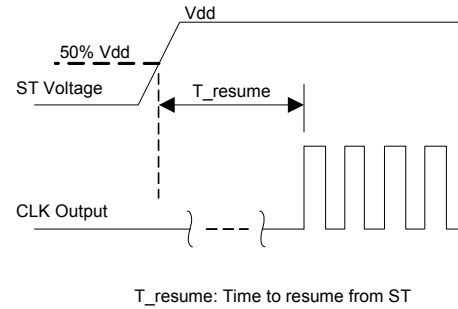


Figure 8. Standby Resume Timing (ST Mode Only)

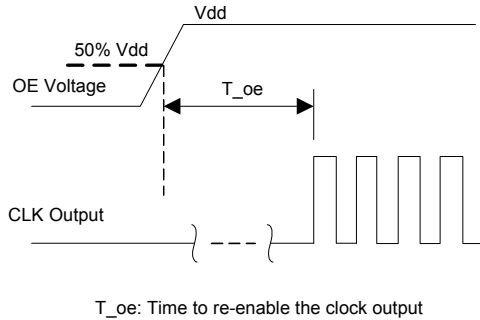


Figure 9. OE Enable Timing (OE Mode Only)

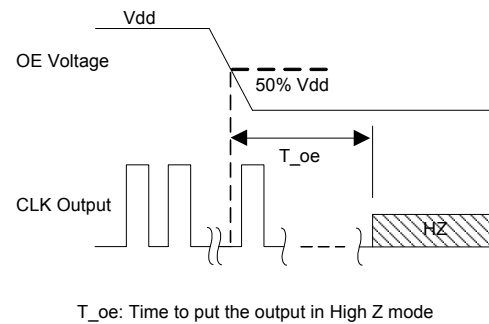


Figure 10. OE Disable Timing (OE Mode Only)

Notes:

13. SiT3809 supports "no runt" pulses and "no glitch" output during startup or resume.
14. SiT3809 supports gated output which is accurate within rated frequency stability from the first cycle.

Instant Samples with Time Machine and Field Programmable Oscillators

SiTime supports a field programmable version of the SiT3809 MEMS VCXO for fast prototyping and real time customization of features. The [field programmable devices](#) (FP devices) are available for all four standard SiT3809 package sizes and can be configured to one's exact specification using the [Time Machine II](#), an USB powered MEMS oscillator programmer.

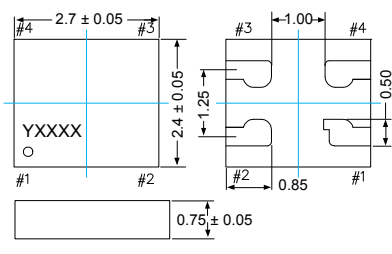
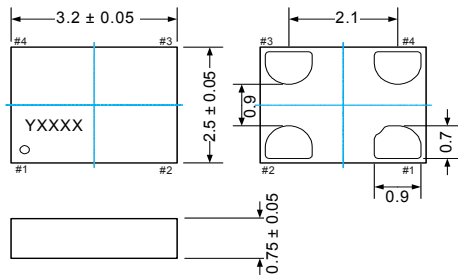
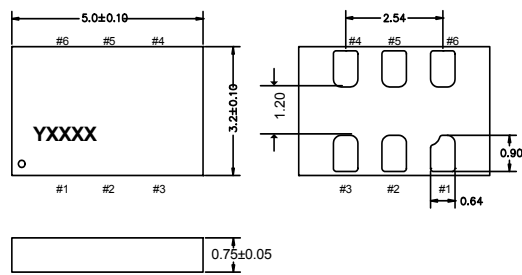
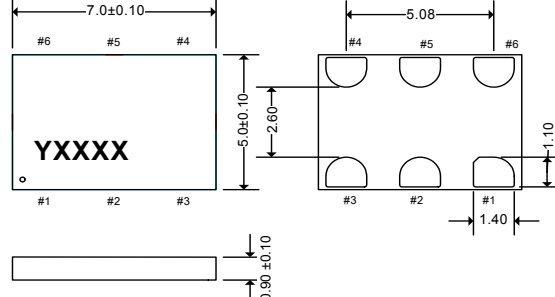
Customizable Features of the SiT3809 FP Devices Include

- Any frequency between 80.000001 MHz to 220 MHz
- Three frequency stability options: ± 10 ppm, ± 25 ppm, ± 50 ppm
- Two operating temperatures: -20 to 70°C or -40 to 85°C
- Four supply voltage options: 1.8V, 2.5V, 2.8V, and 3.3V
- Eight pull range options: ± 25 ppm, ± 50 ppm, ± 100 ppm, ± 150 ppm, ± 200 ppm, ± 400 ppm, ± 800 ppm, ± 1600 ppm

For more information regarding SiTime's field programmable solutions, visit <http://www.sitime.com/time-machine> and <http://www.sitime.com/fp-devices>.

SiT3809 is typically factory-programmed per customer ordering codes for volume delivery.

Dimensions and Patterns

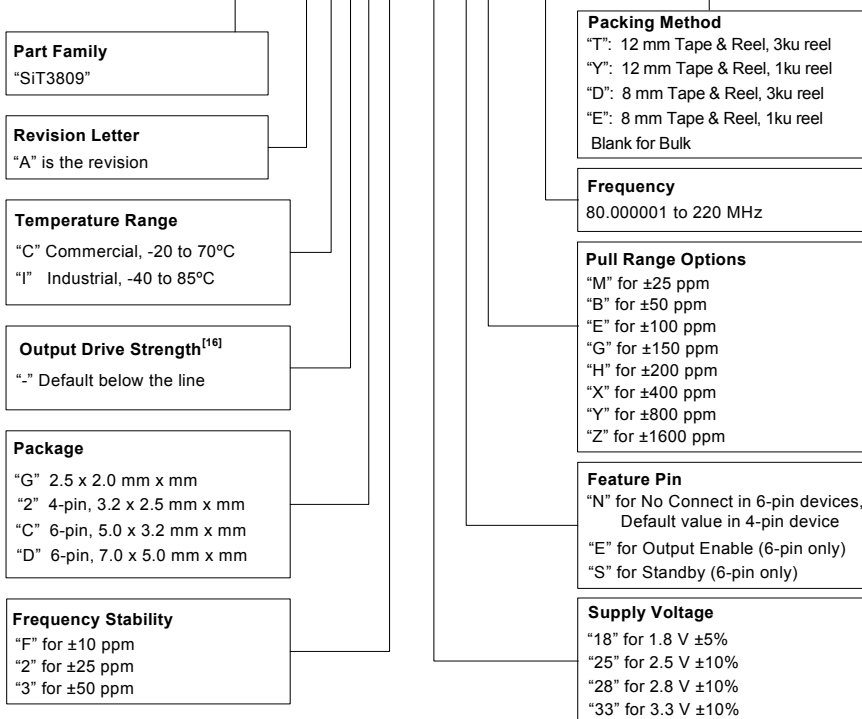
| Package Size – Dimensions (Unit: mm) ^[15] | Recommended Land Pattern (Unit: mm) |
|---|-------------------------------------|
| <p>2.7 x 2.4 x 0.75 mm (100% compatible with 2.5 x 2.0 mm footprint)</p>  | |
| <p>3.2 x 2.5 x 0.75 mm</p>  | |
| <p>5.0 x 3.2 x 0.75 mm</p>  | |
| <p>7.0 x 5.0 x 0.90 mm</p>  | |

Note:

15. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of “Y” will depend on the assembly location of the device.

Ordering Information

SiT3809AC-22-33EH-125.123456D



Note:

16. Contact SiTime for different drive strength to drive multiple loads or to reduce EMI.

Table 7. APR Definition

Absolute pull range (APR) = Nominal pull range (PR) - frequency stability (F_{stab}) - Aging (F_{aging})

| Nominal Pull Range | Frequency Stability | | |
|--------------------|---------------------|-----------|--------|
| | ± 10 | ± 25 | ± 50 |
| | | APR (PPM) | |
| ± 25 | ± 10 | — | — |
| ± 50 | ± 35 | ± 20 | — |
| ± 100 | ± 85 | ± 70 | ± 45 |
| ± 150 | ± 135 | ± 120 | ± 95 |
| ± 200 | ± 185 | ± 170 | ± 145 |
| ± 400 | ± 385 | ± 370 | ± 345 |
| ± 800 | ± 785 | ± 770 | ± 745 |
| ± 1600 | ± 1585 | ± 1570 | ± 1545 |

Table 8. Ordering Codes for Supported Tape & Reel Packing Method^[17]

| Device Size | 12 mm T&R (3ku) | 12 mm T&R (1ku) | 8 mm T&R (3ku) | 8 mm T&R (1ku) |
|--------------|-----------------|-----------------|----------------|----------------|
| 2.5 x 2.0 mm | — | — | D | E |
| 3.2 x 2.5 mm | — | — | D | E |
| 5.0 x 3.2 mm | T | Y | — | — |
| 7.0 x 5.0 mm | T | Y | — | — |

Note:

17. "—" indicates "not available."

Table 9. Additional Information

| Document | Description | Download Link |
|-------------------------------|--|---|
| Manufacturing Notes | Tape & Reel dimension, reflow profile and other manufacturing related info | http://www.sitime.com/component/docman/doc_download/85-manufacturing-notes-for-sitime-oscillators |
| Qualification Reports | RoHS report, reliability reports, composition reports | http://www.sitime.com/support/quality-and-reliability |
| Performance Reports | Additional performance data such as phase noise, current consumption and jitter for selected frequencies | http://www.sitime.com/support/performance-measurement-report |
| Termination Techniques | Termination design recommendations | http://www.sitime.com/support/application-notes |
| Layout Techniques | Layout recommendations | http://www.sitime.com/support/application-notes |
| VCXO Specifications | Definition of key VCXO specifications such as APR and Kv | http://www.sitime.com/support2/documents/AN10020_VCXO_SpecDefinitions_rev1.pdf |
| VCXO in PLL Design | Selection of VCXO parameters and trade-offs in PLL designs | http://www.sitime.com/support2/documents/AN10021_VCXO_PLL_Design_Guidelines_1v0.pdf |

Revision History

Table 10. Datasheet Version and Change Log

| Version | Release Date | Change Summary |
|---------|--------------|---|
| 0.6 | 1/24/2013 | Preliminary |
| 1.0 | 3/18/14 | <ul style="list-style-type: none"> Preliminary removed from title Updated features and application Updated electrical specifications table Updated figure 4, Added new 6-pin device for figure 5 Updated timing diagrams Updated ordering information drawing Updated APR table Updated ordering codes for tape and reel table Reformatted additional information table columns |
| 1.01 | 1/8/15 | <ul style="list-style-type: none"> Corrected CLK and VDD functionality description in Table 2 Revised VIN functionality description in Table 3 |

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Supplemental Information

The Supplemental Information section is not part of the datasheet and is for informational purposes only.

Silicon MEMS Outperforms Quartz

Best Reliability

Silicon is inherently more reliable than quartz. Unlike quartz suppliers, SiTime has in-house MEMS and analog CMOS expertise, which allows SiTime to develop the most reliable products. Figure 1 shows a comparison with quartz technology.

Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced EpiSeal™ process, which eliminates foreign particles and improves long term aging and reliability
- World-class MEMS and CMOS design expertise

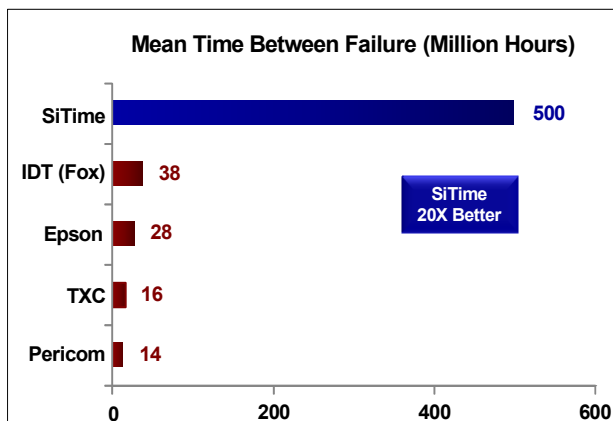


Figure 1. Reliability Comparison^[1]

Best Aging

Unlike quartz, MEMS oscillators have excellent long term aging performance which is why every new SiTime product specifies 10-year aging. A comparison is shown in Figure 2.

Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced EpiSeal process, which eliminates foreign particles and improves long term aging and reliability
- Inherently better immunity of electrostatically driven MEMS resonator

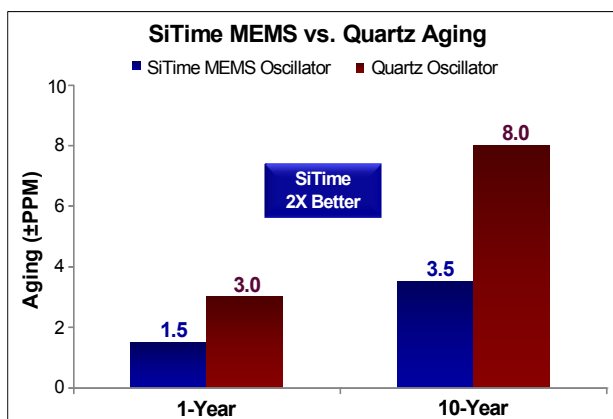


Figure 2. Aging Comparison^[2]

Best Electro Magnetic Susceptibility (EMS)

SiTime's oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

Why is SiTime Best in Class:

- Internal differential architecture for best common mode noise rejection
- Electrostatically driven MEMS resonator is more immune to EMS

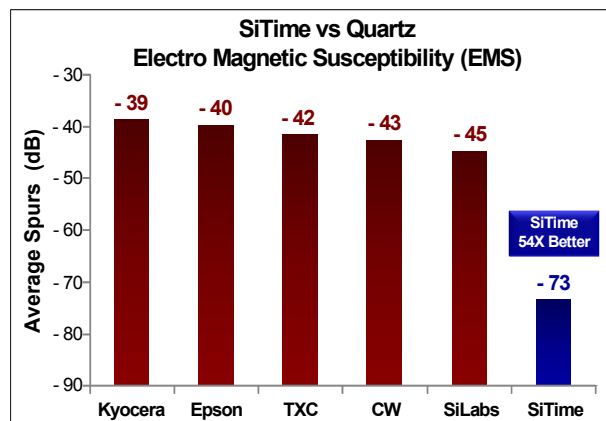


Figure 3. Electro Magnetic Susceptibility (EMS)^[3]

Best Power Supply Noise Rejection

SiTime's MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

Why is SiTime Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- Best analog CMOS design expertise

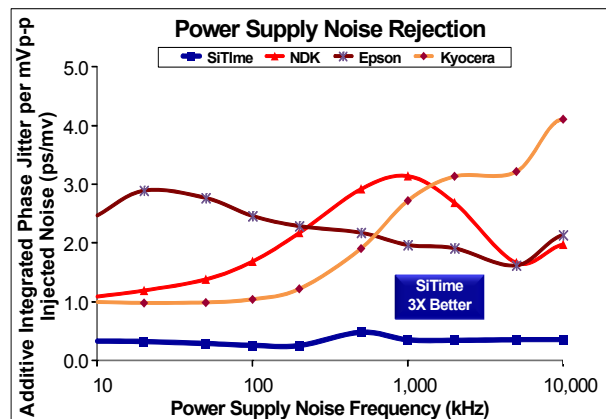


Figure 4. Power Supply Noise Rejection^[4]

Best Vibration Robustness

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

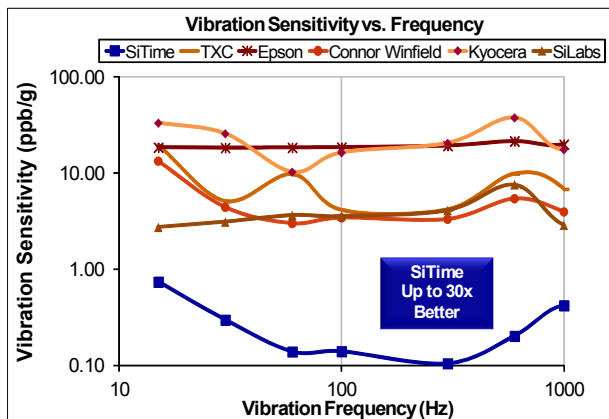


Figure 5. Vibration Robustness^[5]

Best Shock Robustness

SiTime's oscillators can withstand at least 50,000 g shock. They all maintain their electrical performance in operation during shock events. A comparison with quartz devices is shown in Figure 6.

Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

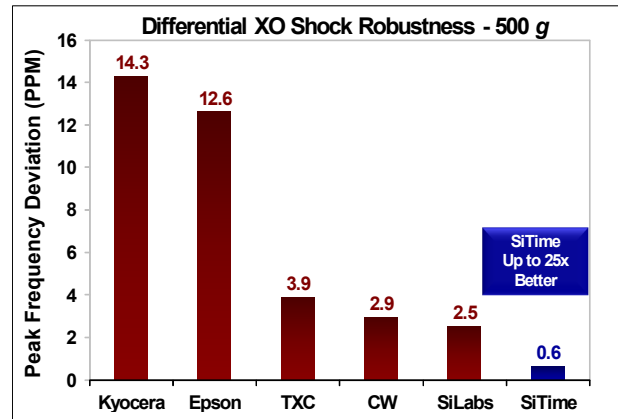


Figure 6. Shock Robustness^[6]

Notes:

1. Data Source: Reliability documents of named companies.
2. Data source: SiTime and quartz oscillator devices datasheets.
3. Test conditions for Electro Magnetic Susceptibility (EMS):
 - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
 - Field strength: 3V/m
 - Radiated signal modulation: AM 1 kHz at 80% depth
 - Carrier frequency scan: 80 MHz – 1 GHz in 1% steps
 - Antenna polarization: Vertical
 - DUT position: Center aligned to antenna

Devices used in this test:
 SiTime, SiT9120AC-1D2-33E156.250000 - MEMS based - 156.25 MHz
 Epson, EG-2102CA 156.2500M-PHPAL3 - SAW based - 156.25 MHz
 TXC, BB-156.250MBE-T - 3rd Overtone quartz based - 156.25 MHz
 Kyocera, KC7050T156.250P30E00 - SAW based - 156.25 MHz
 Connor Winfield (CW), P123-156.25M - 3rd overtone quartz based - 156.25 MHz
 SiLabs, Si590AB-BDG - 3rd overtone quartz based - 156.25 MHz
4. 50 mV pk-pk Sinusoidal voltage.

Devices used in this test:
 SiTime, SiT8208AI-33-33E-25.000000, MEMS based - 25 MHz
 NDK, NZ2523SB-25.6M - quartz based - 25.6 MHz
 Kyocera, KC2016B25M0C1GE00 - quartz based - 25 MHz
 Epson, SG-310SCF-25M0-MB3 - quartz based - 25 MHz
5. **Devices used in this test:** same as EMS test stated in Note 3.
6. Test conditions for shock test:
 - MIL-STD-883F Method 2002
 - Condition A: half sine wave shock pulse, 500-g, 1ms
 - Continuous frequency measurement in 100 μ s gate time for 10 seconds

Devices used in this test: same as EMS test stated in Note 3
7. Additional data, including setup and detailed results, is available upon request to qualified customers. Please contact productsupport@sitime.com.

Document Feedback Form



The Smart Timing Choice™

SiTime values your input in improving our documentation. Click [here](#) for our online feedback form or fill out and email the form below to productsupport@sitime.com.

1. Does the Electrical Characteristics table provide complete information? Yes No

If No, what parameters are missing?

2. Is the organization of this document easy to follow? Yes No

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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
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- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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